

Title (en)  
LIGHT EMITTING DEVICE

Title (de)  
LICHTEMITTIERENDE VORRICHTUNG

Title (fr)  
DISPOSITIF ÉLECTROLUMINESCENT

Publication  
**EP 3067942 A1 20160914 (EN)**

Application  
**EP 16164199 A 20121115**

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Abstract (en)  
A light emitting device according to the embodiment includes a transmissive substrate; a first pattern portion including a plurality of protrusions; a second pattern portion including a plurality of concaves having a width smaller than a width of each protrusion; a light emitting structure disposed under the transmissive substrate and including a first conductive semiconductor layer, a second conductive semiconductor layer and an active layer between the first and second conductive semiconductor layers; a first electrode under the first conductive semiconductor layer; a reflective electrode layer under the second conductive semiconductor layer; a second electrode under the reflective electrode layer; a first connection electrode under the first electrode; a second connection electrode under the second electrode; and an insulating support member disposed around the first electrode and the first connection electrode and around the second electrode and the second connection electrode, wherein the light emitting structure includes a plurality of cells, and the second electrode and second connection electrode are formed in plurality under the plurality of cells.

IPC 8 full level  
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